Multiplex, Inc. 🦳

Photonics for Communications

MTX510E Series 10Gb/s 1550nm Electro-absorption Modulated Laser (EML)

14 Pin Package with G-S-G RF Input



The MTX510E series contain an electro-absorption modulated laser (EML) module consists of a multiquantum-well DFB laser device with 1550nm nominal emission wavelength and a monolithically integrated electro-absorption (EA) modulator in a 14-pin, hermetically-sealed package. State-of-theart, epoxy-free laser-welding is utilized. The laser module also contains a thermoelectric cooler and a monitor photodiode.

The MTX510E series modules are optimized to operate at a bit-rate of 10Gb/s for OC-192 and metro transmission with an excellent pedigree of reliability. The MTX510E module is well suited for short, intermediate and extended reach applications up to 20, 40 and 80 km respectively. Careful control of the output signal for minimum "chirp" allows the MTX510E to provide superior performance and long reach over spans of standard single mode fiber.

The 14 pin package contains a high-speed laser diode, optical isolator, back facet monitor diode, thermistor and thermoelectric cooler. The incorporated thermoelectric cooler keeps the laser chip at a well-controlled temperature. This allows the device to operate over a case temperature range of 0°C to +70°C.

The MTX510E series comes with a standard 1.0 meter single-mode fiber pigtail and an FC/PC connector. Other pigtails fiber types and terminations may be specified as options.

Applications:

 MTX510E series is designed for high-speed telecom and datacom transmissions over spans up to 80km in length in compliance with Telcordia GR-253-CORE (issue 3) LR-2 specifications.

Features:

- Industry standard precision 14-pin package with G-S-G RF input.
- Available for C-band ITU Channels 13 through 60 on 50GHz and 100GHz spacing.
- High-speed design optimized for modulation at 9.95328Gb/s.
- 50 Ohm input impedance match.
- Integrated optical isolator.

Compliance:

 Conforms to the requirements of the European Union Directive 2002/95/EC for the Restriction of Hazardous Substance (RoHS)

| PARAMETER | SYMBOL | CONDITION | MIN | MAX | UNIT |
|-------------------------------------|-------------------|---|-----------------|--------------|------|
| DFB Laser: | | | | | |
| Set temperature for laser operation | T _{SET} | Temperature set for TEC | 20 | 35 | °C |
| Threshold Current | I _{TH} | At T _{SET} , CW operation, BOL | | 30 | mA |
| | | At T _{set} , BOL | 40 | 100 | _ |
| Operating Current | I _{op} | At T _{set} , EOL | 60 | 150 | mA |
| Operating Wavelength | λ | L | 1529.16 | 1567.13 | nm |
| Side-Mode Suppression Ratio | SMSR | At T _{SET} , I _{OP} | 35 | | dB |
| EA Modulator: | | | | | |
| Mark Offset Voltage ¹ | V _{MARK} | DC (on level modulator voltage) | -1.0 | -0.1 | V |
| Peak-to-Peak RF Drive Voltage | V _{PP} | | 2.0 | 2.7 | v |
| Input Impedance | Z _{IN} | | 45 | 55 | Ω |
| Module: | | | | | |
| Extinction Ratio | E _R | V _{MARK} biased, modulated with V _{PP} 20km 40km 80km | 8.2 10 10 | | dB |
| Monitor Photodiode Current | I _{MOD} | | 10 | 1500 | μΑ |
| Modulated Output Power (EOL) | P _{MOD} | I _{OP} = I _{TH} + 50mA 20km 40km 80km | -6 -1 0 | -1 2 4 | dBm |
| Optical Isolation | | | 30 | | dB |
| Operating Case Temperature | T _{CASE} | | 0 | 70 | °C |
| | | 20km at 9.95328 Gb/s, 2^{31} - 1 PRBS NRZ modulated, 400 ps/nm dispersion. BER = 10 ⁻¹² | | 2.0 | dB |
| Chromatic Dispersion Penalty | DP | 40km at 9.95328 Gb/s, 2 ³¹ - 1 PRBS NRZ modulated, 800 ps/nm dispersion. BER = 10 ⁻¹² | | 2.0 | |
| | | 80km at 9.95328 Gb/s, 2 ³¹ - 1 PRBS NRZ modulated, 1600 ps/nm dispersion. BER = 10 ⁻¹² | | 2.0 | |
| High Frequency Cut-Off | F _{3db} | | 8 | | GHz |
| Low Frequency Cut-Off | FLC | | | 100 | kHz |
| RF Return Loss, 50Ω | S ₁₁ | 0.1 to 8GHz | | -8 | |

MTX510E Series

| Rise / Fall Time, 10% - 90% | T _R -T _F | | | 40 | ps |
|-----------------------------------|--------------------------------|---------------------------------|------|------|----|
| TEC thermal capacity ³ | Δ TEC | At Tset, lop ΔTEC = Tcase –Tset | -30 | 45 | °C |
| TEC current | I _{TEC} | At Tset, lop EOL | - | 1.2 | А |
| TEC voltage | Vtec | At Tset, lop EOL | | 2.5 | V |
| TEC AC resistance | Rtec | At Tset, lop EOL | | 1.7 | Ω |
| TEC power dissipation | Ptec | At Tset, lop EOL | | 1.0 | w |
| Thermistor Resistance | R _{TH} | At 25 °C | 9.5 | 10.5 | kΩ |
| Thermistor B Constant | | | 3800 | 4000 | |
| Lead Soldering time | t | Soldering temperature 260 °C, | | 10 | s |

Table Notes: 1. Vmark is the top rail DC voltage applied to the modulator.

Absolute Maximum Operating Ratings

Optimal thermal contact between the housing and the application heat-sink is required.

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Exposure to absolute maximum ratings for extended periods can adversely affect device reliability.

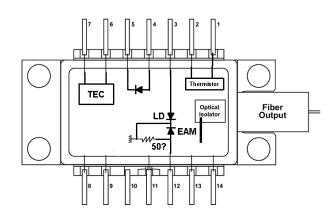
| PARAMETER | SYMBOL | CONDITION | MIN | МАХ | UNIT |
|----------------------------------|-------------------|-----------|------|-----|------|
| Operating Case Temperature Range | T _{CASE} | | -5 | 75 | °C |
| Storage Case Temperature Range | T _{STG} | | -40 | 85 | °C |
| Laser Forward Bias Current | L _{FL} | cw | - | 150 | mA |
| Laser Reverse Voltage | V _{RL} | cw | - | 2 | v |
| Optical Output Power | Р | cw | - | 10 | mW |
| Laser Chip Temperature | T _{LD} | | 15 | 40 | °C |
| Modulator Reverse Voltage | V _{MR} | | - | 5 | v |
| Modulator Forward Voltage | V _{MF} | | - | 1 | v |
| Photodiode Reverse Voltage | V _{PD} | | - | 10 | v |
| Photodiode Forward Current | I _{FPD} | | - | 1 | mA |
| Thermistor Voltage | V _{TH} | | - | 5 | v |
| Thermistor Current | I _{TH} | | - | 2 | mA |
| TEC Current | I _{TEC} | | -1.5 | 1.5 | А |
| TEC Voltage | V _{TH} | | - | 5 | v |

Ordering information:

| ΜΤΧ | X | ХХ | X | XXXX | XXX | XX | XX | -XX | -CXXX |
|-----|-------------|-----------------|-------------|---|------------|---------------------------------------|--------------------|-------------------------------|---|
| | Wavelength: | Data Rate: | Laser Type: | Wavelength: | 5 | Fiber Pigtail Type: | Pigtail Connector: | Reach: | Customized Information: |
| | 5=1550nm | 10= 9.95328Gb/s | E= EML | WCxx= Fixed λ, C channel. WHxx= Fixed λ, H channel. W [blank] = Omitted for Non-ITU | B04=14-Pin | F5= SMF-900 F6= SMF-250 F7= PMF | | S2=20km I2=40km L2=80km | Customized for specific customer requirements |

For example, MTX510EWB04F5SC-I2 has a wavelength 1550nm, Data Rate 9.95328Gb/s, non-ITU, 14-Pin Package, SMF-900 Fiber Pigtail with SC Connector fitted for a 40Km application.

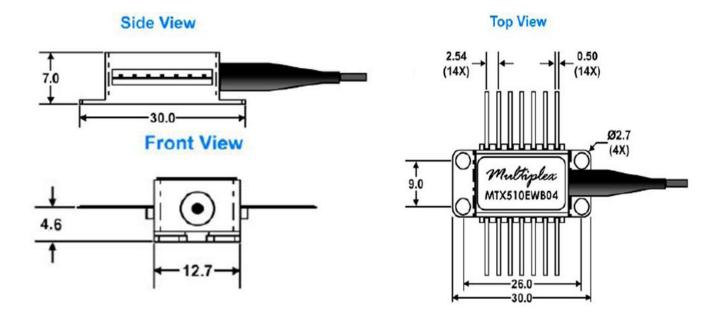
Internal Circuit:



| Pin Number | Description |
|------------|-------------------------------|
| 1 | Thermistor (Resistance=10 kΩ) |
| 2 | Thermistor |
| 3 | Laser Anode |
| 4 | Detector Monitor Anode |
| 5 | Detector Monitor Cathode |
| 6 | Thermoelectric Cooler (+) |
| 7 | Thermoelectric Cooler (-) |
| 8 | N/A |
| 9 | N/A |
| 10 | N/A |
| 11 | Ground |
| 12 | RF Input |
| 13 | Ground |
| 14 | N/A |

MTX510E Series

Mechanical



WARRANTY

Multiplex warrants all standard laser products, when used within the operating limits, against defects in material and workmanship for a period of one year from date of shipment.

QUALITY

Multiplex is qualified to International Standard ISO 9001:2008.

